BTA140 series

GENERAL DESCRIPTION

Passivated triacs in a plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

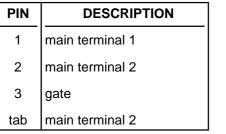
PINNING - TO220AB

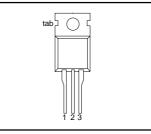
QUICK REFERENCE DATA

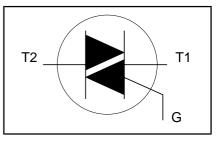
SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V _{drm} I _{t(rms)} I _{tsm}	BTA140- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	600 600 25 190	800 800 25 190	V A A

PIN CONFIGURATION

SYMBOL







LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	AX.	UNIT
V_{DRM}	Repetitive peak off-state voltages		-	-600 600 ¹	-800 800	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 91 \degree C$ full sine wave; $T_j = 25 \degree C$ prior to surge	-	2	:5	A
		t = 20 ms	-		90	A
l ² t	I ² t for fusing	t = 16.7 ms t = 10 ms	-		09 80	A A ² s
dl _⊤ /dt	Repetitive rate of rise of on-state current after	$I_{TM} = 30 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	_		50	
	triggering	T2+ G+	-		0	A/μs
		T2+ G- T2- G-	-		60 60	A/μs A/μs
		T2- G- T2- G+	-		0	A/μs A/μs
I _{GM} P _{GM}	Peak gate current Peak gate power		-		2 5	Á W
$\begin{array}{c} P_{G(AV)} \\ T_{stg} \\ T_{j} \end{array}$	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -	1:	.5 50 25	W °C °C

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 $A/\mu s$.

BTA140 series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air	- -	- - 60	1.0 1.4 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

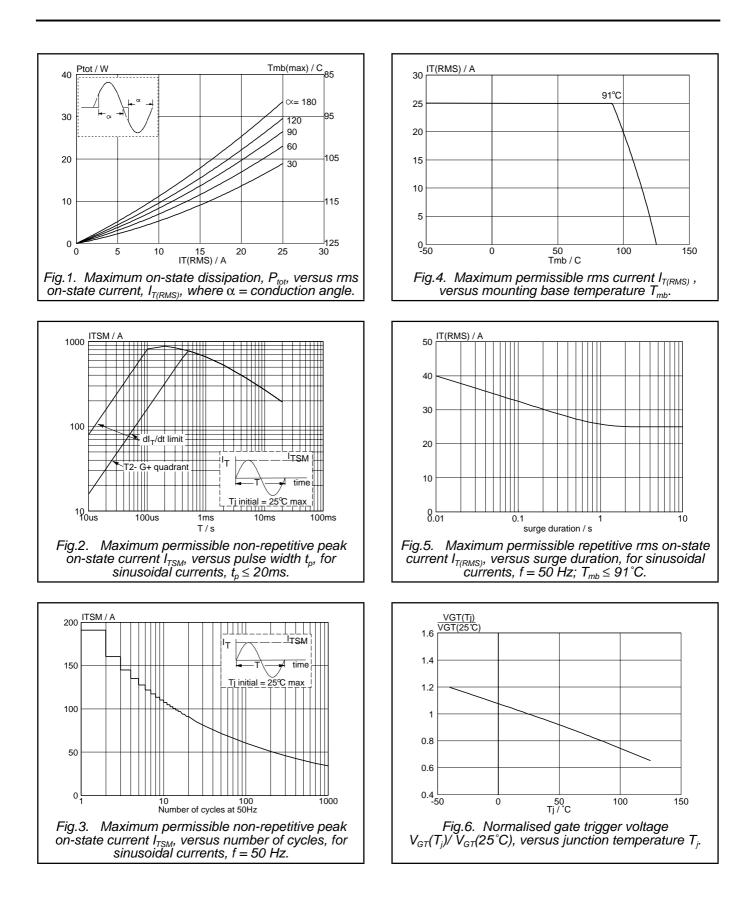
SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$					
			T2+ G+	-	6	35	mA
			T2+ G-	-	10	35	mA
			T2- G-	-	11	35	mA
			T2- G+	-	23	70	mA
I _L	Latching current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$					
			T2+ G+	-	8	40	mA
			T2+ G-	-	30	60	mA
			T2- G-	-	18	40	mA
			T2- G+	-	15	60	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$			_		
			T2+	-	7	30	mA
			T2-	-	12	30	mA
V _T V _{GT}	On-state voltage	$I_{T} = 30 \text{ A}$		-	1.3	1.55	V
V _{GT}	Gate trigger voltage	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$	••	-	0.7	1.5	V
1.		$V_{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{L} = 125$	C	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{\rm D} = V_{\rm DRM(max)}; T_{\rm j} = 125 ^{\circ}{\rm C}$		-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

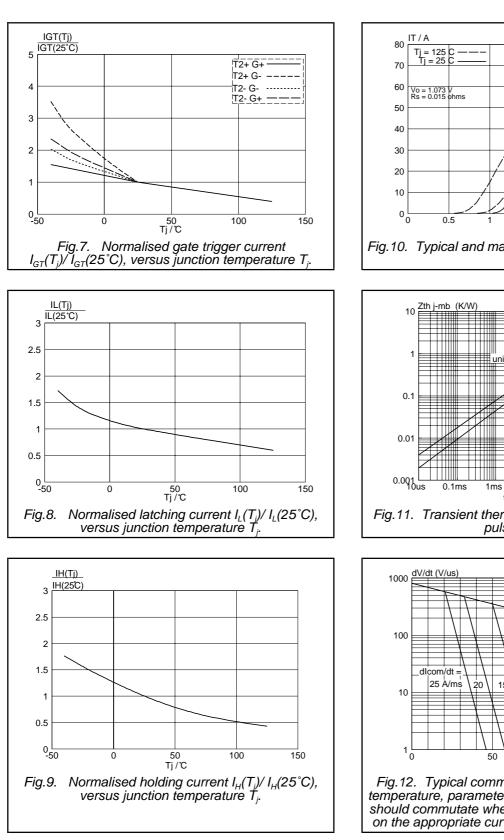
 $T_i = 25$ °C unless otherwise stated

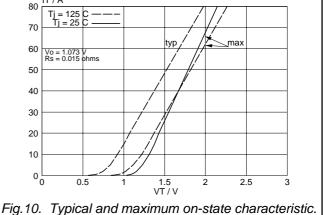
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	100	300	-	V/µs
dV _{com} /dt	off-state voltage Critical rate of change of commutating voltage	exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 95 ^{\circ}\text{C}; \text{ I}_{T(RMS)} = 25 \text{ A};$ $d\text{I}_{com}/dt = 9 \text{ A/ms}; \text{ gate open circuit}$	-	10	-	V/µs
t _{gt}		$I_{TM} = 30 \text{ A}; \text{ V}_{D} = \text{V}_{DRM(max)}; \text{ I}_{G} = 0.1 \text{ A};$ $dI_{G}/dt = 5 \text{ A}/\mu \text{s}$	-	2	-	μs

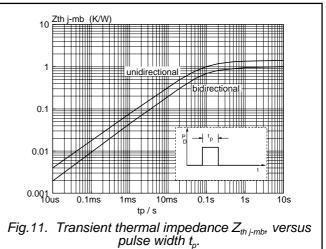
BTA140 series

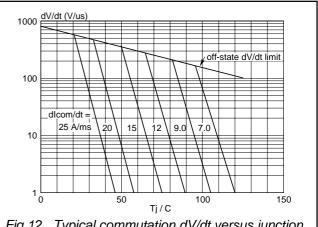


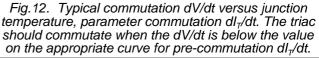
BTA140 series





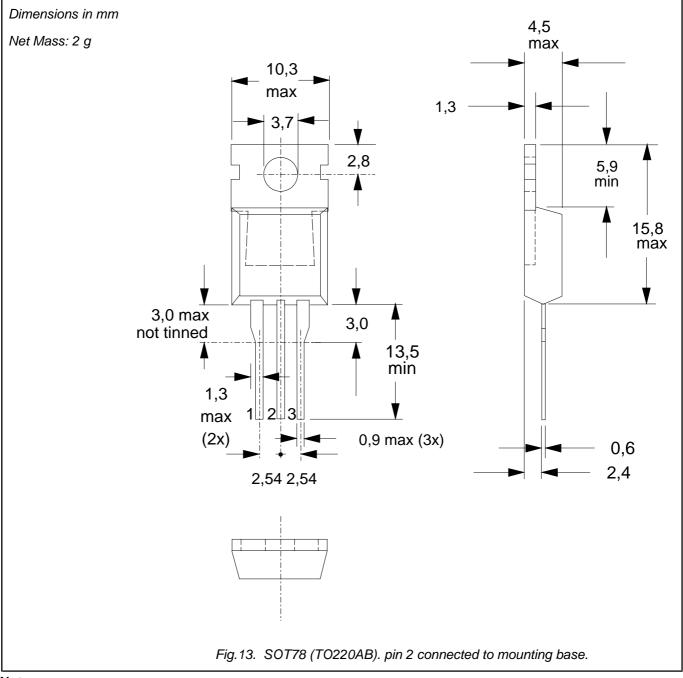






BTA140 series

MECHANICAL DATA



Notes 1. Refer to mounting instructions for SOT78 (TO220) envelopes. 2. Epoxy meets UL94 V0 at 1/8".

BTA140 series

DEFINITIONS

DATA SHEET STATUS				
DATA SHEETPRODUCTDEFINITIONSSTATUS2STATUS3		DEFINITIONS		
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice		
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product		
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A		

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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² Please consult the most recently issued datasheet before initiating or completing a design.

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